Non-Hermitian topology of transport in Chern insulators

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It has recently been shown that signatures of non-Hermitian topology can be realized in a conventional quantum Hall device connected to multiple current sources. These signatures manifest as robust current-voltage characteristics, dictated by the presence of a nontrivial, non-Hermitian topological invariant of the conductance matrix. Chiral edge states are believed to be responsible for this non-Hermitian response, similar to how they lead to a quantized Hall conductivity in the presence of a single current source. Here, we go beyond this paradigm, showing that multi-terminal conductance matrices can exhibit non-Hermitian topological phase transitions that cannot be traced back to the presence and directionality of a boundary-localized chiral mode. By performing quantum transport simulations in the quantum Hall regime of monolayer graphene, we find that when the chemical potential is swept across the zeroth Landau level, unavoidable device imperfections cause the appearance of an additional non-Hermitian phase of the conductance matrix. This highlights graphene as an ideal platform for the study of non-Hermitian topological phase transitions, and is a first step towards exploring how the geometry of quantum devices can be harnessed to produce robust, topologically-protected transport characteristics.

Introduction — A physical system can have a non-Hermitian topological description if it is coupled to an environment and the resulting gains and losses are customized to reach a topological phase [1, 2]. Such a topological phase offers robust characteristics, with potential applications such as light funnels [3], amplifiers [4], and exponentially precise sensors [5, 6]. The experimental realization of these phases usually relies on platforms where gain and loss can be precisely controlled in each individual building block. Examples include ultracold atoms [7], optical systems [8, 9], and meta-materials [3, 10-15].

A recent study takes an alternative approach, which leverages the quantum transport properties of a wellknown Hermitian topological phase - the quantum Hall phase in a GaAs/AlGaAs heterostructure [16]. In the presence of multiple current sources, the current-voltage characteristics of the quantum Hall phase show robust features that originate from the non-Hermitian topology of the conductance matrix, not of the Hamiltonian. The chiral edge modes ensure that charge propagates between neighboring contacts only in one direction, meaning that the multi-terminal conductance matrix becomes numerically equivalent to the Hamiltonian matrix of the Hatano-Nelson (HN) chain [17], a prototypical model of non-Hermitian topology. In effect, each terminal plays the role of a 'site' in the HN chain, while the edge modes propagating between adjacent contacts play the role of nearest-neighbor, one-way 'hoppings.'

Away from the quantum Hall plateau regime, the

bulk becomes conducting and diffusive transport occurs between any pair of contacts, such that the analogy between chiral edge modes and nonreciprocal nearestneighbor hoppings breaks down. All elements of the non-Hermitian conductance matrix become sizeable, potentially leading to additional topological phases and phase transitions that are not the direct consequence of the chiral modes. Here, we demonstrate the emergence of an additional phase in the non-Hermitian, multi-terminal conductance matrix of Chern insulators. This extra phase is not caused by boundary-localized chiral modes, arising instead in the transition region between two quantum Hall plateaus with opposite Chern numbers. The topologically trivial phase is due to the inhomogeneities present in the conductance matrix, which occur in any experimental setup. Our work shows that, beyond the quantum Hall regime, the quality and geometry of multiterminal devices can play an important role in generating robust current-voltage characteristics protected by non-Hermitian topology.

To illustrate this concept, we turn to graphene, one of the most accessible and highly-tunable platforms for realizing quantum Hall physics. Using a toy model, we first highlight the correspondence between chiral edge modes and the non-Hermitian topology of the conductance matrix. This correspondence remains valid even as the chemical potential is swept through the charge neutrality point and the edge modes change direction. Next, we introduce inhomogeneities into the multi-terminal conductance matrix, showing that they cause the emergence of an additional phase.

Transport in graphene and its connection to non-Hermitian topology — We use a toy model for graphene consisting of spinless fermions hopping on a honeycomb lattice. The Hamiltonian takes the form

$$H = t \sum_{\langle ij \rangle} c_i^{\dagger} c_j + \mu \sum_i c_i^{\dagger} c_i, \qquad (1)$$

where μ represents the on-site energy of an electron at the site index i, c_i (c_i^{\dagger}) represent its annihilation (creation) operator, $\langle \ldots \rangle$ denotes nearest neighbors, and tis the hopping parameter. The unit cells are labeled by integers (n_x, n_y) in the $\vec{e_x}, \vec{e_y}$ directions, respectively [see Fig. 1(a)].

We introduce a perpendicular magnetic field by changing the vertical hoppings in Fig. 1(a) from t to $t \exp(i\phi n_x)$, where $\phi/2\pi$ is the flux per hexagon, in units of the flux quantum. This gaps out the Dirac cones and results in the formation of Landau levels, symmetrically distributed around the charge neutrality point, E = 0[18] (see the supplemental material (SM) for details [19]). Since the model is spinless, sweeping the chemical potential from $\mu > 0$ to $\mu < 0$ reverses the edge mode propagation direction from counter-clockwise to clockwise, leading to a direct transition between phases with Chern numbers +1 and -1.

Using the Kwant package [20], we attach N equallyspaced ideal leads to the boundary of a finite-sized, diskshaped system, as shown in Fig. 1(b) for N = 6. Numerical details are described in the SM [19]. This models an experimental setup in which N contacts are connected to a graphene sample. In the linear regime, the currents injected into each of the contacts, $\vec{I} = (I_1, \ldots, I_N)$, are related to the potentials on each of the contacts, $\vec{V} = (V_1, \ldots, V_N)$, as $\vec{I} = G\vec{V}$, where G is the $N \times N$ conductance matrix. At zero-temperature and in the zero bias voltage limit, the elements of G take the form

$$G_{ij} = \frac{e^2}{h} \left[\delta_{ij} \mathcal{N}_j - \operatorname{tr} \left(S_{ij} S_{ij}^{\dagger} \right) \right].$$
 (2)

Here, e is the electric charge, h is Planck's constant, δ_{ij} denotes the Kronecker delta, \mathcal{N}_j is the number of propagating modes in lead j, and tr denotes the trace. The matrix S_{ij} is a block of the full, multi-terminal scattering matrix, containing the probability amplitudes for a particle to be transmitted from any incoming mode of lead j to any outgoing mode of lead i.

For the six-terminal system shown in Fig. 1(b), setting $\mu = -0.2t$ and $\phi = 0.18$, such that the system is deep in the quantum Hall phase with Chern number -1, leads to the conductance matrix shown in Fig. 1(c). This matrix is identical to the non-Hermitian Hamiltonian matrix of the Hatano-Nelson tight-binding model [17], a chain of orbitals connected by nonreciprocal nearest-neighbor



FIG. 1. Panel (a): Graphene lattice with two sites (shown as white and black circles) in each unit cell (marked by the yellow dashed contour). \vec{e}_x and \vec{e}_y are the Bravais vectors and t is the nearest neighbor hopping. Panel (b): Schematic of a graphene disk with six contacts (blue) attached to its boundaries and labeled from one to six. The transmission between adjacent leads in the clockwise and anticlockwise directions is represented by red and green arrows, respectively. Panel (c): Conductance matrix G for a disk of graphene with six leads [as in (b)], deep in a quantum Hall phase with Chern number -1 $(\mu/t = -0.2, \phi = 0.18)$. The conductance (in units of e^2/h) is quantized between adjacent leads in the downstream direction of the edge modes and is zero in the opposite direction. The full conductance matrix is equivalent to a Hatano-Nelson Hamiltonian under PBC whereas the sub-matrix (enclosed by blue dashed lines) is equivalent to the same under OBC. Panel (d): SPD plotted for the G matrix in panel (c) against the site index (lead index) on a log-linear scale under OBC (non-Hermitian skin effect) and PBC.

hoppings. Thus, each of the diagonal elements G_{ii} can be thought of as being analogous to the onsite energy of a site in the fictitious chain. The off-diagonal elements are analogous to hopping integrals connecting the different fictitious sites. In this case, each of the sites has an onsite energy equal to +1, one-way hoppings equal to -1 connect the j^{th} and $(j-1)^{\text{th}}$ sites, and since $G_{61} = -1$, the chain has periodic boundary conditions (PBC). Realizing an analogue of the Hatano-Nelson model with open boundary conditions (OBC) can be done by grounding the 6th contact (setting the potential $V_6 = 0$). In this case the currents and voltages corresponding to the first five terminals would be related by the 5 × 5 conductance sub-matrix, G_{OBC} , shown by the dashed box in Fig. 1(c).

The nontrivial topology of the Hatano-Nelson Hamiltonian matrix, and thus of the multi-terminal conductance matrix, results in robust current-voltage characteristics. A transport regime in which the current vector is proportional to the voltage vector $\vec{I} \propto \vec{V}$ can only be reached provided that these vectors are eigenvectors of the conductance matrix. In the OBC case (grounded 6th contact), all eigenvectors are exponentially localized to one end of the fictitious Hatano-Nelson chain, a non-Hermitian topological phenomenon referred to as the non-Hermitian skin effect [21, 22]. This can be seen from the probability density summed over all right eigenvectors v_n of the conductance matrix, $\text{SPD} = \sum_n |v_n|^2$. Thus, when $\vec{I} \propto \vec{V}$ the currents and voltages on terminals 1 to 5 follow the exponentially decaying pattern shown in Fig. 1(d).

In contrast, for the PBC setup, when $\vec{I} \propto \vec{V}$ the six currents and voltages do not show an exponential profile. Both of these proportionality regimes can be reached in a robust and predictable way by means of iterative transport measurements, as shown experimentally in Ref. [16].

Inhomogeneity and topological phase transitions We are interested in studying the topology of the conductance matrix away from the quantum Hall plateau regime, when bulk transport is significant and all elements of G are nonzero. To this end, we follow Refs. [16, 23], and focus only on the OBC setup in the following. The N^{th} contact is grounded at all times and only the $(N-1) \times (N-1)$ sub-block of the conductance matrix, G_{OBC} , is considered. We use a topological invariant, $w_{\rm PD}$, that can be determined directly from this conductance matrix, and which predicts the existence of a non-Hermitian skin effect. To compute it, we first subtract the average of the diagonal elements from the conductance matrix, $\hat{G} = G_{OBC} - \lambda \mathbb{1}$, where $\lambda = \text{tr}(G_{\text{OBC}})/(N-1)$ and $\mathbb{1}$ is the identity matrix. Writing the polar decomposition of this matrix, G = QP, where Q is unitary and P is a positive-definite matrix, vields

$$w_{\rm PD}(\hat{G}) = \mathcal{T}(Q^{\dagger}[Q, X]), \qquad (3)$$

where $X = \text{diag}(1, 2, \dots, N-1)$ encodes the lead index, and \mathcal{T} is the trace per unit volume evaluated over the middle indices, far from the ends (see SM for details [19]).

As expected, we confirm that $w_{\rm PD}$ correctly predicts the appearance of a non-Hermitian skin effect in the conductance matrix of Fig. 1(d). Deep in the quantum Hall plateau regime, where the boundary-localized chiral modes produce one-way nearest-neighbor hoppings of the fictitious Hatano-Nelson chain, the invariant in Eq. (3) is locked to the Chern number. We have verified that sweeping the chemical potential across the charge neutrality point leads to a direct transition in the Chern number from +1 to -1, and simultaneously to a direct transition of $w_{\rm PD}$, from -1 to +1. Correspondingly, there is a change of direction in the non-Hermitian skin effect: all eigenvectors of the conductance matrix are all localized either on the left or the right side of the chain, depending on the sign of μ .

In any experiment, we expect that the conductance matrix will be inhomogeneous due to multiple factors.



FIG. 2. $\langle w_{\rm PD} \rangle$ evaluated for conductance matrices of a monolayer spinless graphene disk with 10 leads, one of which is grounded (9 lead OBC matrix) as a function of varying δ/t and chemical potential μ/t . The trivial phase ($\langle w_{\rm PD} \rangle = 0$) becomes more prominent close to the charge neutrality point $\mu/t = 0$ as δ increases. Here, $\phi = 0.18$.

These include the varying quality of different contacts, unequal distances between them, as well as disorder and defects in the sample. For simplicity, we obtain inhomogeneous conductance matrices G by randomly changing the potential on each site of the honeycomb lattice, $\mu \rightarrow \mu + \delta_i$, where δ_i is chosen from a uniform distribution $(-\delta, \delta)$.

The average non-Hermitian topological invariant of the conductance matrix can be expressed as:

$$\langle w_{\rm PD} \rangle = \frac{\sum_{i=1}^{n} w_{\rm PD}(\hat{G}_i)}{n},\tag{4}$$

for *n* independent realizations of the random onsite potential, each producing a different conductance matrix G_i . Figure 2 shows that for $\delta = 0$ the conductance matrix exhibits a direct transition from $w_{\rm PD} = +1$ to -1as the chemical potential is swept across the charge neutrality point, as mentioned above. Turning on inhomogeneities, however, leads to the appearance of a trivial phase of the conductance matrix, $\langle w_{\rm PD} \rangle = 0$, for which the current-voltage characteristics do not show the exponential profile of the non-Hermitian skin effect (see SM for details [19]). We observe that increasing δ leads to an enlargement of this phase, which appears for a wider range of chemical potential μ .

The intervening trivial non-Hermitian phase of the conductance matrix appears in a region where the bulk of the graphene is conducting, due to the fact that random potential fluctuations broaden the zeroth Landau level. However, it is not caused by the presence of conducting bulk modes. To show this, we consider a different averaging scheme, where we first average the conductance matrix over the random realizations of onsite disorder,



FIG. 3. Panel (a): Absolute value of disorder-averaged conductances $\langle G \rangle_{1,2}$ (purple) and $\langle G \rangle_{2,1}$ (green), showing the transition between two quantum Hall phases with Chern numbers C = 1 and C = -1, for a spinless graphene disk with N = 40 contacts. In these phases, the conductance through the bulk is negligible, as indicated by the $\langle G \rangle_{1,20} \times 100$ (multiplied by a factor of 100 for ease of visibility) (blue). This bulk conductance becomes non-zero in the transition region between the two quantum Hall phases, indicating the diffusive transport regime [see SM for details [19]]. Panel (b): evaluated $\langle w_{\rm PD} \rangle$ shows the presence of a trivial phase close to $\mu/t = 0$ between two non-Hermitian topological phases (+1 and -1). This is in contrast to $\langle w_{\rm PD}\rangle_2$ which shows a direct transition between the two phases. Here, $\delta/t = 1.2$, and $\phi = 0.18$. Panel (c): A 6 × 6 conductance sub-matrix at $\mu = -0.04t$ for a single realization of onsite disorder, indicating the inhomogeneities in its entries. Panel (d): A 6×6 sub-matrix of the disorder-averaged conductance matrix $\langle G \rangle$ at $\mu = -0.04t$ exhibiting the uniformity in its entries (see SM for details [19]).

and only afterwards compute the topological invariant:

$$\langle w_{\rm PD} \rangle_2 = w_{\rm PD} \left(\frac{1}{n} \sum_{i=1}^n \hat{G}_i \right).$$
 (5)

This procedure leads to a conductance matrix with uniform entries on each diagonal, where the broadening of the zeroth Landau level is still present, but does not produce an extra non-Hermitian phase in the conductance matrix (see Fig. 3).

The true reason for emergence of the extra phase between $\langle w_{\rm PD} \rangle = \pm 1$ phases is due to inhomogeneities in the conductance matrix and is a natural consequence of the current conservation rules. Since the sum of all elements of G over any column must vanish due to Kirchhoff's laws, $\sum_{i=1}^{L} G_{ij} = 0$, random conductance fluctuations between different pairs of leads necessarily lead to random changes on the conductance matrix diagonal. On the level of the fictitious, 1D Hatano-Nelson chain simulated by G, this corresponds to the presence of onsite disorder, which is known to lead to an extra $\langle w_{\rm PD} \rangle = 0$ phase (see Ref. [23] and SM [19]).

Conclusion — We have theoretically investigated the non-Hermitian topological behavior associated with multiple-current-source transport in Chern insulators, using the quantum Hall phases of a honeycomb graphene model as an example. Our simulations demonstrated the presence and robustness of non-Hermitian phases in the conductance matrix of this system, which can easily be tuned through chemical potential variations. This variation can be achieved in practice via gate voltage adjustments, making graphene a promising platform to realize current-voltage relations protected non-Hermitian topology.

Interestingly, we found that inhomogeneities in the conductance matrix, which can arise, e.g. due to varying contact quality or inter-contact distance lead to the emergence of an additional, trivial non-Hermitian phase in the system's conductance matrix. This implies that away from the quantum Hall plateau regime, the quality and geometry of quantum devices may play a decisive role in producing transport properties associated with non-Hermitian topology. Further, while we have focused on a graphene toy model for simplicity, we expect this behavior to be generic to a larger class of Chern insulators, including those realized in magnetically doped topological insulators [24].

Data availability— The data and code used to generate the figures are available at [25].

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Supplemental Material to: Non-Hermitian topology of transport in Chern insulators

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In this Supplemental Material, we provide more details on our numerical simulations, including a scaling analysis of the extra non-Hermitian phase appearing due to inhomogeneities in the conductance matrix. Further, we highlight the presence/absence of the non-Hermitian skin effect in the averaged/individual conductance matrices, respectively, and also show that the appearance of an intervening phase is also a featured of the original Hatano-Nelson chain in the presence of onsite disorder.

BANDSTRUCTURE

In this section, we present the energy band diagrams for the graphene toy model described in the main text. We consider the system in a ribbon geometry with translational invariance along the $\vec{e_y}$ direction. We fix L = 100unit cells in the finite width direction $\vec{e_x}$,

In the absence of a magnetic flux through the system, the spectrum has a gapless Dirac cone structure with two Dirac cones connected by zig-zag edge modes [see Fig. 1(a)].

In the presence of a magnetic field, a gap opens in this spectrum and Landau levels emerge in the bulk [see Fig. 1(b)] alongside edge localized propagating boundary modes. Here, a Landau level exists at the charge neutrality point (E = 0) which separates two regions of opposite Chern numbers.

DETAILS OF NUMERICAL SIMULATIONS

This section provides details of the numerical simulations for the results in the main text. The graphene toy model is described on a honeycomb lattice using the Kwant package [1]. Here, the lattice constant is equal to 1, and all lengths are measured in its units.

For Fig. 1 of the main text, the radius of the finitesized disk is fixed at r = 40. We attach 6 equally spaced ideal leads to the sites of the system close to the disk's outer boundary in an approximately 10×10 area. The scattering problem is solved at zero bias using Kwant and the transmission probabilities between each pair of distinct leads are used to generate the full conductance matrix G.

For Fig. 2 of the main text, we similarly create a diskshaped system with r = 60 and attach 10 ideal leads



FIG. 1. Bandstructure of a ribbon of the graphene toy model with translation invariance along the $\vec{e_y}$ direction $(\mu/t = 0)$. Panel (a), $\phi = 0$: Dirac cone spectra in the absence of a magnetic field. Panel (b), $\phi = 0.18$: Landau levels emerge in the presence of a magnetic field, alongside unidirectional propagating boundary-localized modes at the ribbon's edges. The color scale represents the probability density of energy eigenstates integrated over half of the total number of unit cells in the finite direction ($0 \le n_x \le L/2$). Eigenstates localized at opposite boundaries are colored in red and blue, respectively.

close to its boundaries. This provides a full 10×10 conductance matrix. To evaluate the $\langle w_{\rm PD} \rangle$ invariant here, we consider the last lead as grounded and work with the 9×9 $G_{\rm OBC}$ sub-matrix. While evaluating the trace per unit volume in Eq. (3) and Eq. (4), we average over 3 sites close to the middle of the chain, i.e. $\lfloor N/2 \rfloor, \lfloor N/2 \rfloor + 1, \lfloor N/2 \rfloor + 2$ where N is the number of terminals in the OBC case and $\lfloor x \rfloor$ is the greatest integer function of x. For N = 9, this corresponds to the 4th, 5th, and 6th entries. Here, the results are averaged over n = 400 independent disorder realizations of the G

matrix.

For Fig. 3 of the main text, we construct a disk of radius r = 240 and attach 40 leads to its outer boundary. The resulting OBC conductance matrix upon grounding the last lead is 39×39 . The average conductance matrix is evaluated here as $\langle G \rangle = (1/n) \sum_{j=1}^{n} G_j$ with n = 3000. In panel (b) of Fig. 3, the evaluation of $\langle w_{\rm PD} \rangle$ and $\langle w_{\rm PD} \rangle_2$ follow the same choice of volume trace as in Fig. 2.

EXTRA NON-HERMITIAN PHASE

In Fig. 3 of the main text, we showed the existence of an extra non-Hermitian phase for OBC conductance matrices corresponding to a system with 40 leads and one of the leads considered grounded. This extra non-Hermitian phase scales with the size of the conductance matrix N. We show this by constructing the same 40 lead disk as in Fig. 3 of the main text but now grounding p out of the 40 leads. This provides us a $(40-p) \times (40-p)$ conductance matrix under OBC. The scaling behavior of the $\langle w_{\rm PD} \rangle$ (averaged over 3000 independent onsite disorder realizations) is shown in Fig. 2 for different choices of p corresponding to different sizes N of the OBC conductance matrix.



FIG. 2. $\langle w_{\rm PD} \rangle$ for different sizes N of the OBC conductance matrix $G_{\rm OBC}$ as a function of the chemical potential μ indicating the presence of the trivial phase for different number of leads. Here, $\delta = 1.2t$.

Next, in Fig. 3 (a-d), we tune the chemical potential μ to access this extra non-Hermitian phase and explicitly show that the average conductance matrix $\langle G \rangle$ (averaged over n = 3000 independent configurations) here is uniform whereas the conductance matrix G_i for a single random onsite disorder realization i of the system has inhomogeneities. Both of these 39×39 matrices are obtained from the 40 lead setup described above upon

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grounding of the last lead.

This extra non-Hermitian phase corresponds to a current-voltage characteristic that does not show an exponential profile of the non-Hermitian skin effect. The SPD for the inhomogeneous conductance matrix G_i shows an absence of a piling up of its eigenstates towards one end of the chain whereas the SPD for the averaged conductance matrix shows this behavior $\langle G \rangle$, [see Fig. 3(e)].



FIG. 3. Panels (a-d): Uniformity of the average conductance matrix. Entries of the diagonals of different orders j (integervalued) above the main diagonal (j = 0) of a 39 × 39 OBC conductance matrix (blue) and the average conductance matrix $\langle G \rangle$ (red). The average conductance matrix has uniform entries on its diagonals for diagonals of all orders j = 1, 2, 3, 4 [panels (a), (b), (c), (d), respectively] whereas the entries of G_i are inhomogeneous. Panel (e): SPD plotted on a logarithmic scale for a 39 × 39 inhomogeneous conductance matrix G_i (green) and uniform average conductance matrix $\langle G \rangle$ (yellow). Due to inhomogeneities, the SPD for G_i shows an absence of the non-Hermitian skin effect, i.e. it is not exponentially localized towards one end of the chain, whereas the SPD for the uniform conductance matrix exhibits it. In all the panels above, $\delta = 1.2t$, and $\mu = -0.04t$.

CONDUCTANCE MATRIX: FINITE LONGER-RANGE COUPLINGS

Consider the graphene toy model with onsite disorder δ in a finite-sized disk of radius r = 60 and 10 leads attached to its boundaries. Transport simulations are done for n = 400 independent onsite disorder realizations of the system resulting in an average conductance matrix $\langle G \rangle$.

As the system transitions across a broadened zeroth Landau level by varying the chemical potential μ , the previously topologically protected boundary modes lose their protection, leading to transport through the bulk of the system. We demonstrate this phenomenon within the scope of our multi-terminal transport simulations, as outlined below.



FIG. 4. Average multi-terminal conductance response for a monolayer disk of graphene. Panel (a): Absolute difference of average conductance $|\langle G \rangle_{1,2} - \langle G \rangle_{2,1}|$ highlighting two quantum Hall phases $(|\langle G \rangle_{1,2} - \langle G \rangle_{2,1}| = 1)$ separated by a broadened zeroth Landau level at the charge neutrality point $\mu/t = 0$, whose width increases with an increase in δ . Panels (b, c, d): Average conductance through the bulk of the system $(\langle G \rangle_{1,3}, \langle G \rangle_{1,4}, \langle G \rangle_{1,5})$. These are zero in the quantum Hall regime (edge transport) and take on finite values while transitioning between them (bulk transport). Here, $\phi = 0.18$.

The absolute difference between $\langle G \rangle_{1,2}$ and $\langle G \rangle_{2,1}$ [see Fig. 4(a)] as a function of μ/t and δ/t shows the two quantum Hall phases $(|\langle G \rangle_{1,2} - \langle G \rangle_{2,1}| \approx 1)$ and the transition region $(|\langle G \rangle_{1,2} - \langle G \rangle_{2,1}| \neq 1)$ between them. The broadening of the zeroth Landau level here increases with the strength of δ/t .

The conductance through the bulk of the system, $\langle G \rangle_{1,3}, \langle G \rangle_{1,4}$, and $\langle G \rangle_{1,5}$ (see Fig. 4(b-d)) is zero when the system resides in a quantum Hall regime, indicating no bulk transport. However, as the system transitions through the broadened zeroth Landau level, these entries become nonzero, reflecting the emergence of bulk transport. Consequently, the resulting conductance matrix exhibits finite couplings between all pairs of leads.

TRIVIAL PHASE IN THE HATANO-NELSON MODEL

In the main text, we showed how inhomogeneities in the entries of the conductance matrix G in a multiterminal setup of monolayer graphene could produce a trivial phase as a natural consequence of the current conservation rules. It is also known that a finite chain of the Hatano-Nelson model can host a trivial phase in the presence of finite onsite disorder [2]. Here, we leverage this knowledge and illustrate how applying constraints that mimic the current conservation rules in $G(\sum_{i=1}^{N} G_{ij} = 0)$ onto the Hamiltonian matrix of a disordered Hatano-Nelson chain would lead to a trivial phase.

Consider a disordered version of the Hatano-Nelson model [2]:

$$H_{\rm HN} = \sum_{i} J_{\rm right}^{i} \left| j + 1 \right\rangle \left\langle j \right| + J_{\rm left}^{i} \left| j \right\rangle \left\langle j + 1 \right|, \quad (1)$$

where $J_{\text{right}}^i = (t_0 + g) + W_{\text{R}} w_{\text{R}}^i$ and $J_{\text{left}}^i = (t_0 - g) + W_{\text{L}} w_{\text{L}}^i$ are real numbers denoting the hoppings towards the right and left, respectively. Here, w_{L}^i , and w_{R}^i are random numbers independently drawn from a uniform distribution (-0.5, 0.5].

The Hamiltonian matrix representing a finite chain of length L for this model under open boundary conditions is given by:

$$H_{\rm HN} = \begin{pmatrix} 0 & J_{\rm left}^1 & & & \\ J_{\rm right}^2 & 0 & J_{\rm left}^2 & & & \\ & J_{\rm right}^3 & 0 & \ddots & & \\ & & \ddots & \ddots & \ddots & \\ & & & \ddots & 0 & J_{\rm left}^{L-1} \\ & & & & J_{\rm right}^L & 0 \end{pmatrix}, \quad (2)$$

while under periodic boundary conditions, this matrix includes two additional terms $(H_{\text{HN}_{1,\text{L}}} = J_{\text{right}}^1 \text{ and} H_{\text{HN}_{\text{L},1}} = J_{\text{left}}^L).$

We now apply a constraint on the Hamiltonian matrix $H_{\rm HN}$ in Eq. (1) under PBC as $\sum_{i=1}^{L} H_{\rm HN_{ij}} = 0$, and the diagonal elements are modified accordingly. This leads to the disorder in the hopping terms getting translated onto the disorder in the diagonal entries of the Hamiltonian matrix in Eq. (1). Similar to conductance matrices, the Hamiltonian matrix for a Hatano-Nelson chain of length L - 1 with OBC is the $(L - 1 \times L - 1)$ sub-matrix of the corresponding Hamiltonian matrix with PBC which omits the hoppings to and from the last site of the chain.



FIG. 5. Panels (a,b): $\langle w_{\rm PD} \rangle$ in the (g, $W_{\rm R}$) phase space showing non-trivial non-Hermitian topological phases +1 and -1 separated by a trivial insulating phase when the diagonal entries of $H_{\rm HN}$ are constrained to satisfy the condition: sum of columns of the Hamiltonian matrix under PBC is zero; $W_{\rm R} = W_{\rm L}, W_{\rm R} = 2W_{\rm L}$ respectively. Panel (c): $\langle w_{\rm PD} \rangle$ in the (g, $W_{\rm R}$) phase space highlighting two non-trivial non-Hermitian topological phases (+1 and -1) when the diagonal entries of $H_{\rm HN}$ are manually set to zero. Here, we set $t_0 =$ $1, W = E_{\rm B} = 0, L = 100.$

To describe the non-Hermitian topological phases for a finite size chain of this model under OBC, we evaluate the $w_{\rm PD}$ invariant [see Eq. (3) of the main text] by replacing G with the constrained disordered Hamiltonian $H_{\rm HN}$. Labelling the Hamiltonian matrix for a disordered configuration indexed i as $H_{\rm HN_i}$ and setting the corresponding base point $E_{\rm B} = {\rm tr}(H_{\rm HN_i})/L$, we evaluate

$$\langle w_{\rm PD} \rangle = \frac{\sum_{i=1}^{n} w_{\rm PD}(H_{\rm HN_i})}{n}, \qquad (3)$$

where n is the total number of disorder configurations. This disorder averaging procedure is similar to the one described in Eq. (4) for conductance matrices G in the main text. We find that a trivial phase appears in the system alongside two non-Hermitian topological phases in the presence of disorder [see Fig. 5(a, b)]. If, on the other hand, we do not apply the constraint as above, we find that the trivial phase vanishes [see Fig. 5(c)]. Thus the presence of disorder in the hopping terms, and the physical constraint on its diagonal entries is responsible for the emergence of a trivial phase in this system.

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